

(19)
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H05B 33/00

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(43)

10-2004-0058446
2004 07 05

(21) 10-2002-0084577
(22) 2002 12 26

(71) . 20

(72) 305 701

1488-39 502

(74)
:

(54)

가 / 가 ,
가 ,

가

8g

1

2

3 2 ii-ii

4a 4i 2 ii-ii

5

6 1 .
 7 2 .
 8a 8g, 9a 9g, 10a 10g, 11a 11g 7 Ila-Ila, Ilb-Ilb, Ilc-Ilc, Ild
 -Ild , Ilc-Ilc , Ild-Ild , Ila-Ila , Ilb-Ilb .
 210 : 216 :
 224a : 224b :
 224 : 228 :
 232 : 246 :
 247 : 256 :
 274 : 276 :
 278 : ch :
 T_D :

(Organic Electroluminescent Device)
 (Active-Matrix Organic Electroluminescent Device)

가 가 가 가 , .

(encapsulation) 가 PDP(Plasma Display Panel)

(frame) 가 가 가 (C_{ST} ; storage capacitance)

가 가 가 , , ,

4) (42), (42) (34) (32) (C_{ST}) (3)

, 1 (58) (64) (66)

(I) (I) (1) (32)

(52) (30), (C_{ST}) 1 (40), (54)

, (42) 2 (44), 1 (58) (50) 가 3 1

4 (40, 44, 54, 60) () .

, 4a 4i 2 ii-ii (exposure), (development) (ph

otolithography)

4a (1) 1 (30) (30)

, 1 (32a ; active layer) (34)

, 4b, 4a (32a), 2 (36) 1 (38), 2

4c, 4b (40) 3 1 (40) (34), 1

(42) 2, 3

, 4d (32a), 4c (42), 3 1, 2 (46a, 46b) (48)

) 가 2 (44) .

) (32a) (iiib) . (iiia)

, (32a) (32b ; ohmic contact layer), (32a) (32b)

(32) .

, 4e (4d 46a) 3 (42) 5 (4d 48) 1

, (50) (iiib) (32b) (iiiia) (50)

(32b) (52) . (4d 46b)

T_D) (32), (38), (50, 52) (

, (42) 1 (34) (52) (C_{ST}) .

(40)

4f 가 3 4e (54) 4 6

, 4g (4f 56) (50) 4

, 7 (I) 1 (58) .

4h (I) 4g 1 (58) 5 1 (62) 가 8 4 (60) .

4 (60) (T_D) .

62) 1 (58) , 4i (64) 1 5 (4h
2 (66) . (64)

1 (58) , 5 (64)
1 (58) (work function) 가 ,

5 ,

1 (70) 1, 2 (70, 90)
(80) , 1 (80) (T_D) (T_D)
1 (72) , 1 (72)
(74) , 1 (74) 2 (76) .

(E) 1, 2 (72, 76) 1, 2 (72, 76) 1 (72) (74)
(74) , (74)

)가 2 (90) , 2 (90) (E) (92)
(94)가 (92)

(94)가 2 (90) 2 (76) .

1, 2 (70, 90) 가 (85) .

가 , 1,000 .

가 가 가

가

2

가 .

() , 1,2 , 1 () 2

; 1 2 ; 2 1

(a-Si) 가 ;

가 ;

가

1 , 1 , 2 가 , 2

2 , 1 PR(photo-resist)

; 1 1 1 2

3 2 4 , 1 1

1 2 5 가 ,

; 1 1 3 6 ,

3 7 , 1

1 2 2 , 1 1
 2
 1 , 4 ,
 , 7 ,
 -- 1 --
 6 1 ,
 , 1, 2 (110, 150)
 1 (110, 150) (140) (140) (T_D) (T_D)
 (142) (142) (142) (T_D)
 , (T_D) (112), (114), (116) (118)
 (142) (118)
 , 2 (150) 1 (152) , 1 (152)
 (160) (156a, 156b, 156c) 2 (162) (160)
 , (160) 1 (152) 1 (154)
 (156a, 156b, 156c) , 2 (162) 2 (1)
 58) ,
 , 1 (152) , 2 (162) , 1 (154)
 , 2 (158)
 , 1, 2 (152, 162) 1, 2 (152, 162) (160)
 (E)
 T_D) , 가 (142) 2 (162) , ()
 (142) 가 (142) 2 (162)
 , 1, 2 (110, 150) 가 (170) , 1, 2 (110, 150)
 (142) , (E) (140)
 , 3 2 ,
 , 가 / 가 가 ,

-- 2 --

7 2 .

(236) , 1 (213) (212) , 1 (212) 2 (236)

(212) (T_S)가 (214) , (236) (T_S) (226) , (226)

22) (230) , (214), (226) (230) (2)

(213) (212) .

(T_S) (213) (T_D)가

(T_D) (212)

(230) (216) , (216) (228)

(232) , (236) (216), (228) (232) (228)

(224)

(228) (246) (278) , (278)

(251) (213) .

(232) (IV) (276)

(278) (276)

(IV) 2 .

(IV)

(230) (213) (234)

(213) (C_{ST}) .

(212), (236), (213) (218), (218),

(238), (219)가 , (218), (219) (244)

(236) (238), 1 (242), 1 (242), 1 (244)

(276) (284) (280), 2 (282), 2

(213) (212) (213) , (212)

(213) (239) (212) , (236) (213)

(213) (239)

(238) (219) 가 ,

-- 3 --

8a 8g, 9a 9g, 10a 10g, 11a 11g 7 IIa-IIa, IIb-IIb, IIc-IIc, II d
 -II d , IIc-IIc , II d-II d , IIa-IIa , IIb-IIb

8a, 9a, 10a, 11a , (210) 1 1 (216),
 (218), (219) . (219)

1 , , PR , PR ,
 가 , PR , PR ,

8b, 9b, 10b, 11b , (216), (218), (219) 1
 , (a-Si), (n+ a-Si) 1
 (220) , (a-Si), (n+ a-Si) 2
 (216) (224) , (224a) , (n+ a-Si)
 (224) , (a-Si) (224a) , (n+ a-Si)
 (224b) . (Si
 Nx) , 1 , (Si

8c, 9c, 10c, 11c , 3 (220) (218), (219)
 1 (221), 1 (223) .

8d, 9d, 10d, 11d , (224), 1 (221), 1 (223)
 2 (228) , 4 (224)
 (221), 1 (III) (238) , 1
 (242) 1 (223) (218), (219) 1
 (244)

(III) , 2 , (219) ,

, 2 (Mo), (Ti), (Cr)
 (W) .

, (224a) (228) (232) (224b) ,
 (216), (224), (228) (224a) (ch) .
 (232) (T_D)

8e, 9e, 10e, 11e , (T_D) (238), 1 (242) 1
), (244) , 2 (228)
 (232), (238), 1 (242) , 5 (244)
 (246), (247), (250), 2 (248), 2
 (252) 가 (256)

2 , ,

8f, 9f, 10f, 11f , (256) 3 6 , (I
 V) (274)

(IV) ,

2

3

8g, 9g, 10g, 11g , (274) , 3 (274) 7
 , (247) (232) , (278) , (248) ()
 250) (276) , (246) (228) (280) , 2 (252) 1 1
 (242) 2 (282) , 2
 (244) 2 (284)
 , (278)

가 , , 가 가 / 가

(57)

1.

1 () 2 () , 1, 2
 , 1, 2

1 1 ;

1 2 ;

2 , 가 ;

, (a-Si) 가 ;

가 ;

;

2.

1 ,

, , ;
 , 1 , 2 , 5 1
 , , 1 1 , 1 1 가 ,
 ;

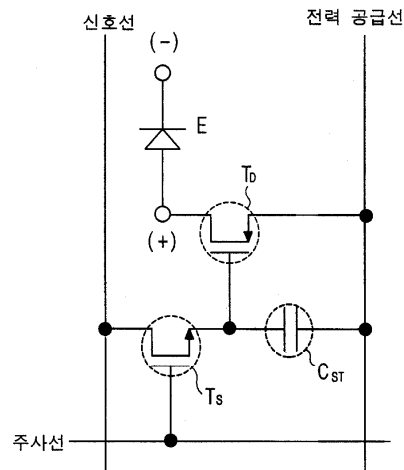
3 6 , ;
 3 7 , , 1
 1 1 2 2 , 1 , 1

9.
 8 ,
 1 , 4 , ,

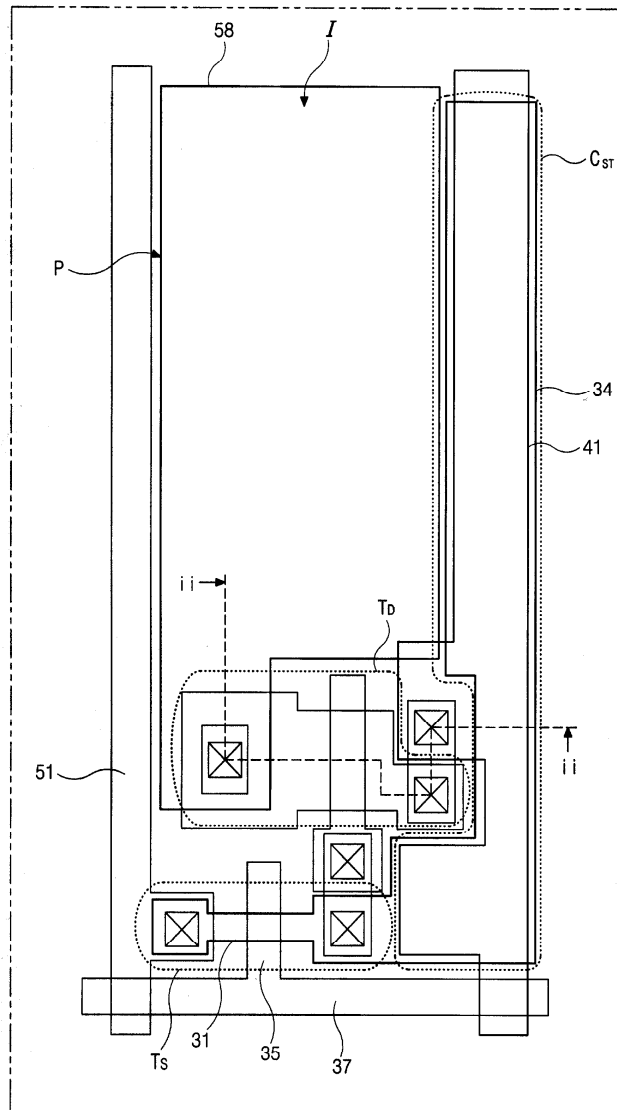
10.
 8 ,

11.
 9 10 ,
 7 ,

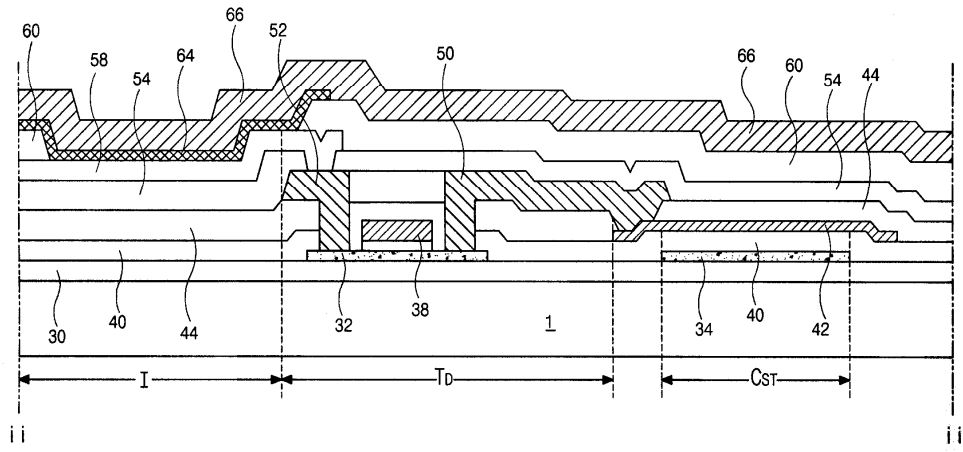
1



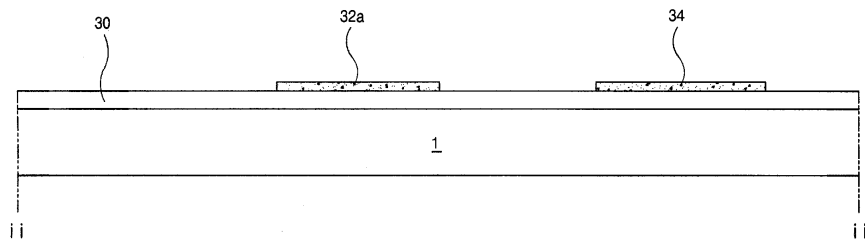
2



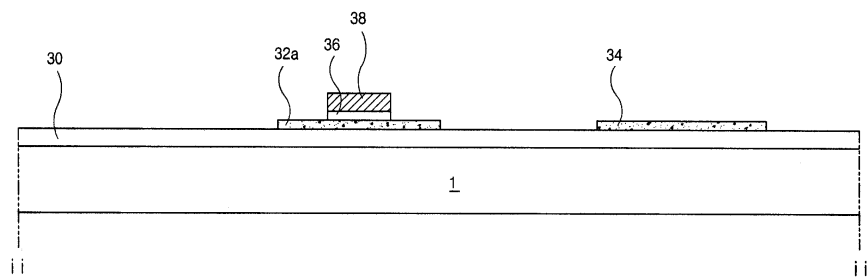
3



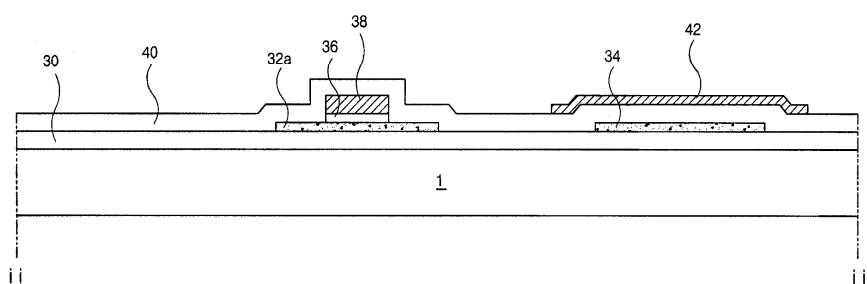
4a



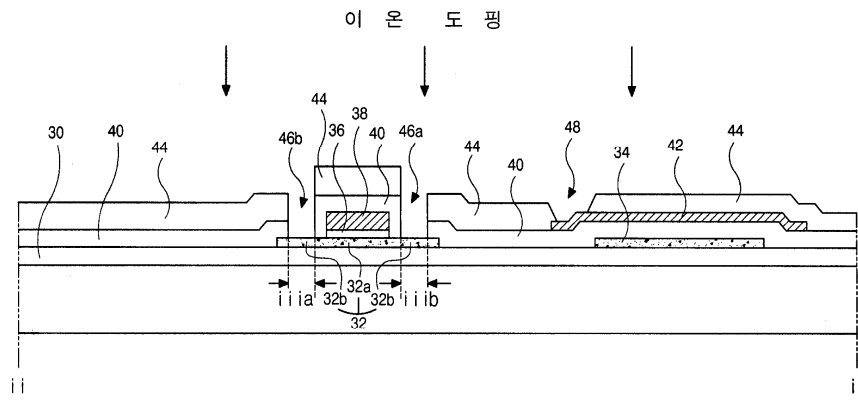
4b



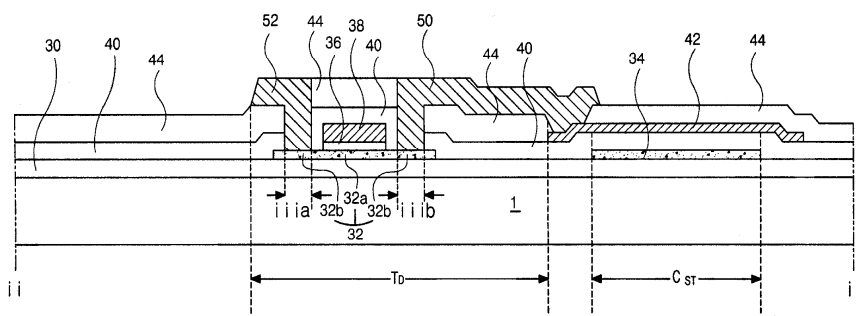
4c



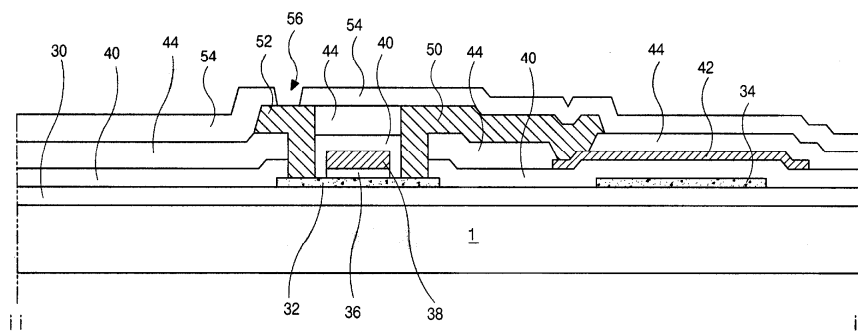
4d



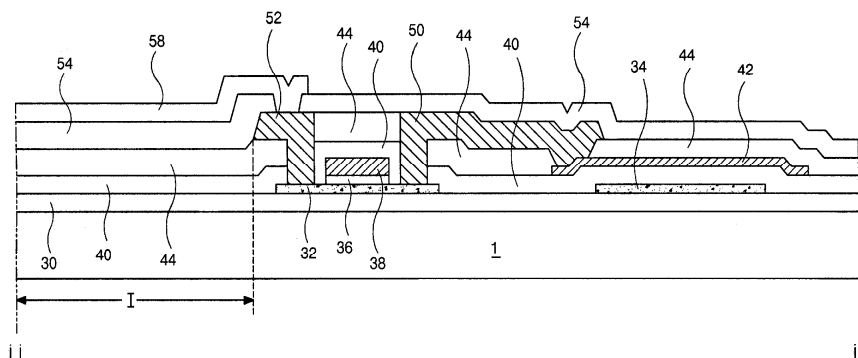
4e



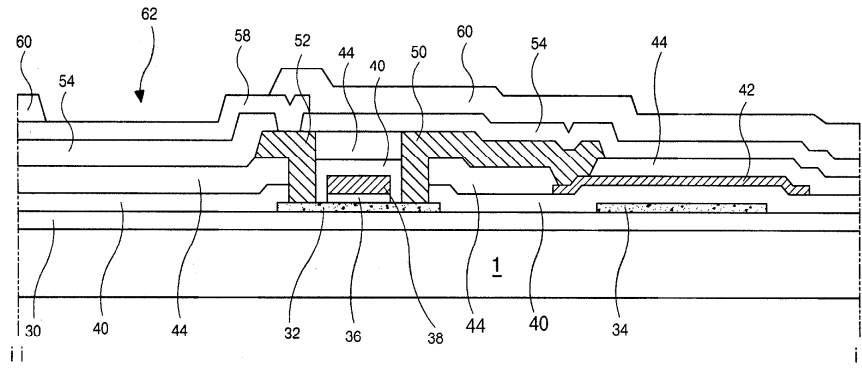
4f



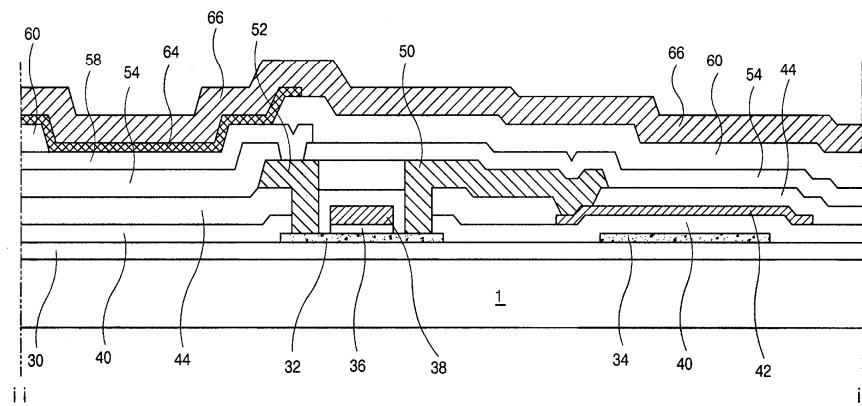
4g



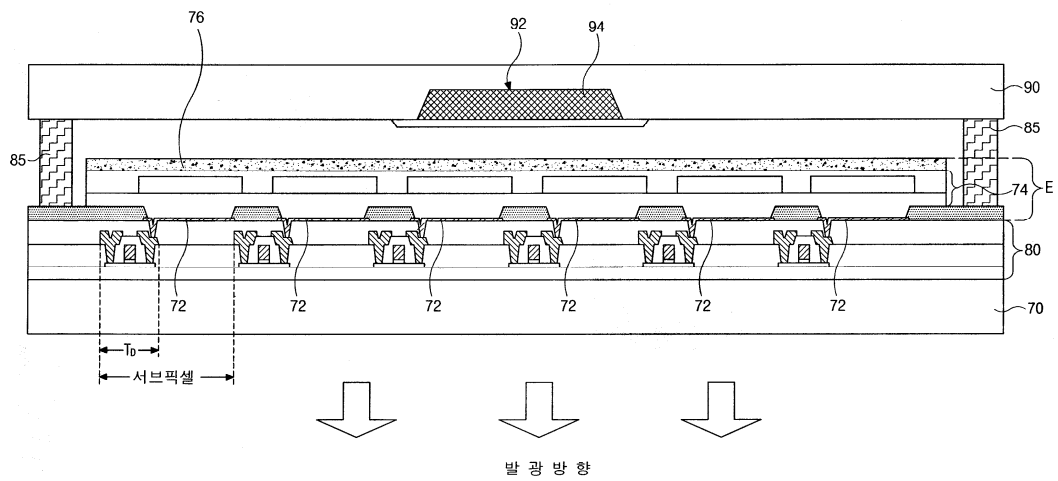
4h



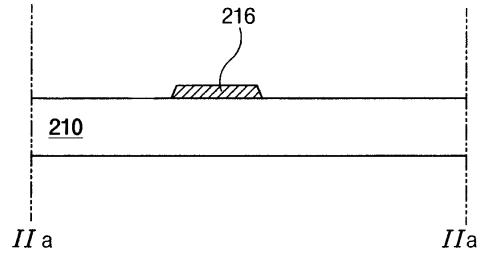
4i



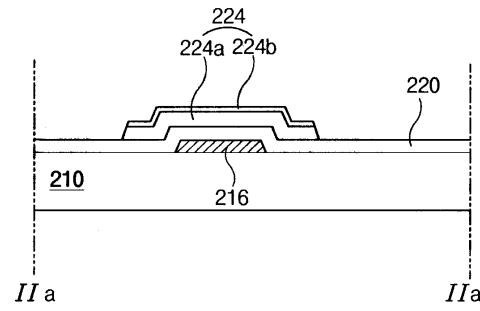
5



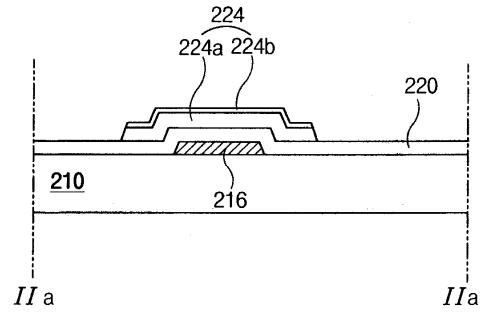
8a



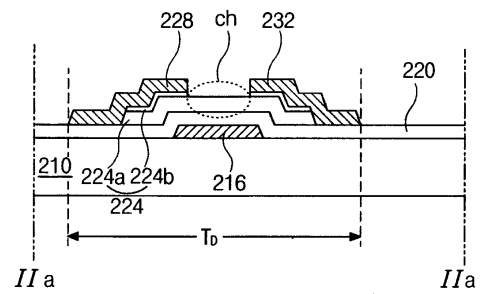
8b



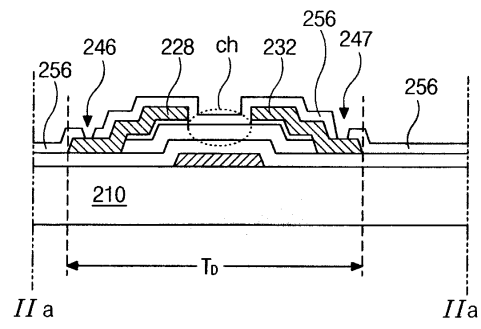
8c



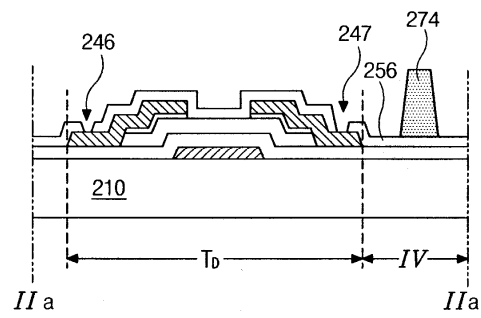
8d



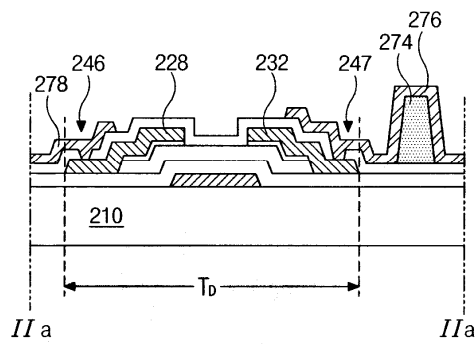
8e



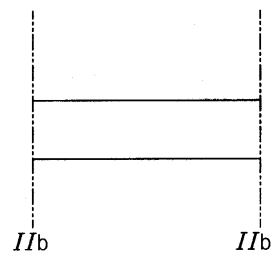
8f



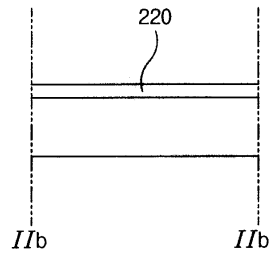
8g



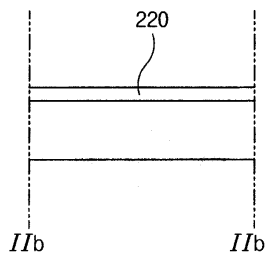
9a



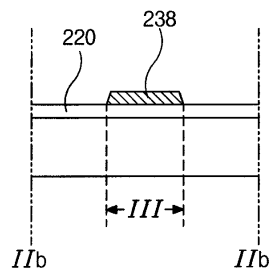
9b



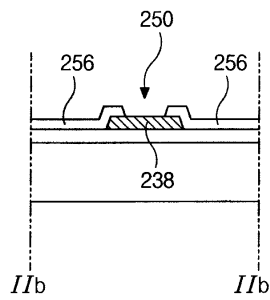
9c



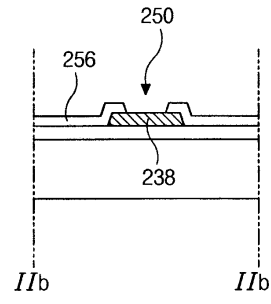
9d



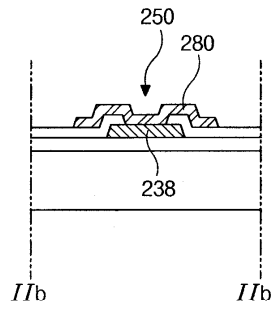
9e



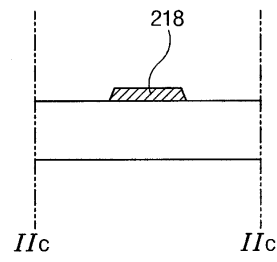
9f



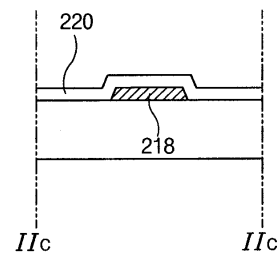
9g



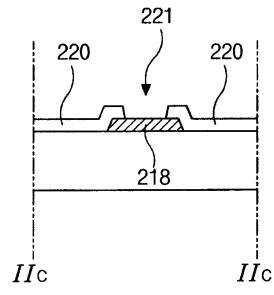
10a



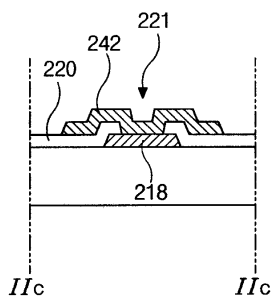
10b



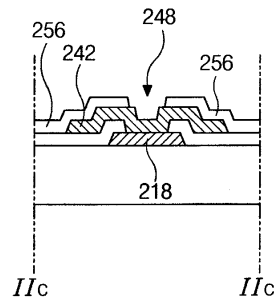
10c



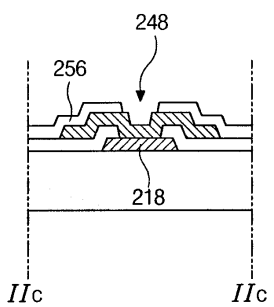
10d



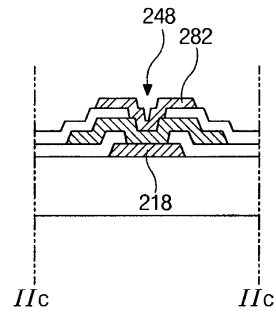
10e



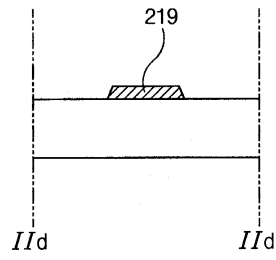
10f



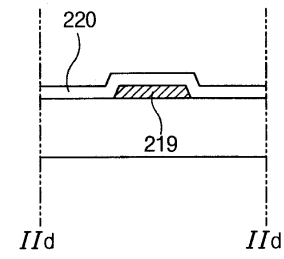
10g



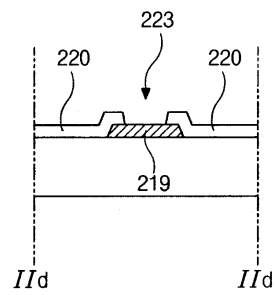
11a



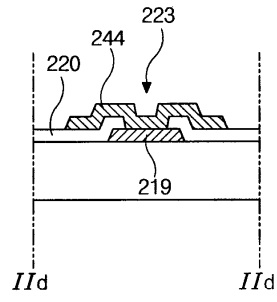
11b



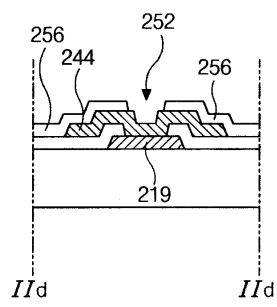
11c



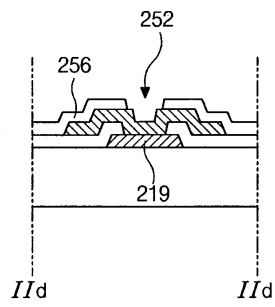
11d



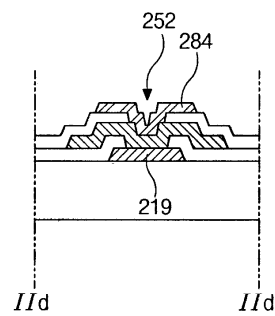
11e



11f



11g



专利名称(译)	双面板型有机电致发光器件及其制造方法		
公开(公告)号	KR1020040058446A	公开(公告)日	2004-07-05
申请号	KR1020020084577	申请日	2002-12-26
[标]申请(专利权)人(译)	乐金显示有限公司		
申请(专利权)人(译)	LG显示器有限公司		
当前申请(专利权)人(译)	LG显示器有限公司		
[标]发明人	PARK JAEYONG 박재용 CHO SOHAENG 조소행		
发明人	박재용 조소행		
IPC分类号	H01L51/50 H01L27/32 G09F9/30 H05B33/10 H01L29/78 H05B33/00		
CPC分类号	H01L27/3262 H01L27/3276 H01L2251/5315 H01L27/3253 H01L27/3265		
代理人(译)	贞媛KI		
其他公开文献	KR100484092B1		
外部链接	Espacenet		

摘要(译)

根据本发明的双面板型有机电致发光器件及其制造方法。首先，由于在不同基板上形成阵列器件和有机发光二极管器件，可以提高产量和生产管理效率。有机发光二极管器件可以增加产品周期，其次，对于使用非晶硅材料的反向交错TFT结构的草药，低温工艺是可能的，它是顶部发射型。根据掩模处理装订上的栅极图案和电源图案的形成，尽管添加了单独的电接触图案，但是掩模计数减少并且可以包括处理简化。

